

DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

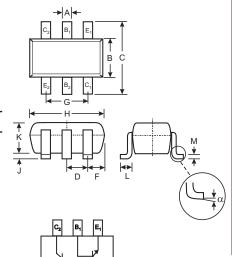
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT5401)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)

Mechanical Data

Case: SOT-363

 Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0

- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking (See Page 2): K4N
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approx.)



| SOT-363 | | | | | | | |
|----------------------|--------|---------|--|--|--|--|--|
| Dim | Min | Max | | | | | |
| Α | 0.10 | 0.30 | | | | | |
| В | 1.15 | 1.35 | | | | | |
| С | 2.00 | 2.20 | | | | | |
| D | 0.65 N | Nominal | | | | | |
| F | 0.30 | 0.40 | | | | | |
| Н | 1.80 | 2.20 | | | | | |
| J | _ | 0.10 | | | | | |
| K | 0.90 | 1.00 | | | | | |
| L | 0.25 | 0.40 | | | | | |
| М | 0.10 | 0.25 | | | | | |
| α | 0° | 8° | | | | | |
| All Dimensions in mm | | | | | | | |

Maximum Ratings @ T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit | |
|--|-----------------------------------|-------------|------|--|
| Collector-Base Voltage | V _{CBO} | 180 | V | |
| Collector-Emitter Voltage | V _{CEO} | 160 | V | |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V | |
| Collector Current - Continuous (Note 1) | Ic | 200 | mA | |
| Power Dissipation (Note 1, 2) | P _d | 200 | mW | |
| Thermal Resistance, Junction to Ambient (Note 1) | R ₀ JA | 625 | °C/W | |
| Operating and Storage and Temperature Range | T _j , T _{STG} | -55 to +150 | °C | |

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

- 2. Maximum combined dissipation.
- 3. No purposefully added lead.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition | | | | |
|--------------------------------------|----------------------|----------------|--------------|----------|---|--|--|--|--|
| OFF CHARACTERISTICS (Note 4) | | | | | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | 180 | _ | V | $I_C = 100 \mu A, I_E = 0$ | | | | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 160 | _ | V | $I_C = 1.0 \text{mA}, I_B = 0$ | | | | |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | 6.0 | _ | V | $I_E = 10\mu A, I_C = 0$ | | | | |
| Collector Cutoff Current | I _{CBO} | _ | 50 | nA μA | V _{CB} = 120V, I _E = 0 V _{CB} = 120V, I _E = 0, T _A = 100°C | | | | |
| Emitter Cutoff Current | I _{EBO} | _ | 50 | nA | V _{EB} = 4.0V, I _C = 0 | | | | |
| ON CHARACTERISTICS (Note 4) | | | | | | | | | |
| DC Current Gain | h _{FE} | 80 80 30 | 250 — | _ | $\begin{array}{c} I_C = 1.0 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_C = 10 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_C = 50 \text{mA}, \ V_{CE} = 5.0 \text{V} \end{array}$ | | | | |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | _ | 0.15 0.20 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA | | | | |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | _ | 1.0 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA | | | | |
| SMALL SIGNAL CHARACTERISTICS | | | | | | | | | |
| Output Capacitance | C _{obo} | | 6.0 | pF | $V_{CB} = 10V, f = 1.0MHz, I_E = 0$ | | | | |
| Small Signal Current Gain | h _{fe} | 50 | 250 | _ | $V_{CE} = 10V, I_{C} = 1.0mA,$ f = 1.0kHz | | | | |
| Current Gain-Bandwidth Product | f⊤ | 100 | 300 | MHz | V _{CE} = 10V, I _C = 10mA, f = 100MHz | | | | |
| Noise Figure | NF | _ | 8.0 | dB | $V_{CE} = 5.0V, I_{C} = 200\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$ | | | | |

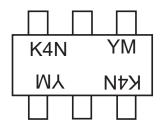
Ordering Information (Note 5)

| Device | Packaging | Shipping | | | |
|--------------|-----------|------------------|--|--|--|
| MMDT5551-7-F | SOT-363 | 3000/Tape & Reel | | | |

Notes: 4. Short duration test pulse used to minimize self-heating effect.

5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

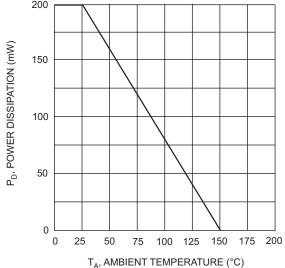


K4N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

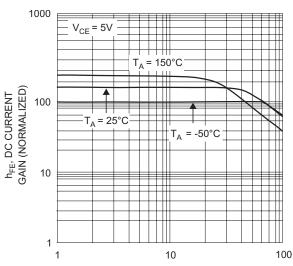
Date Code Key

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 |
|-------|------|------|-------|------|------|------|------|------|------|------|------|------|
| Code | J | K | L | М | N | Р | R | S | Т | U | V | W |
| Month | Jan | Feb | March | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

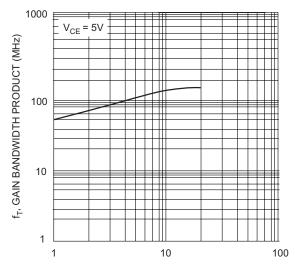




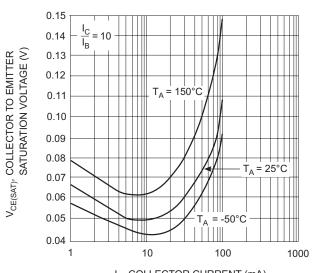
T_A, AMBIENT TEMPERATURE (°C)
Fig. 1, Max Power Dissipation vs
Ambient Temperature



I_C, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 5, Gain Bandwidth Product vs. Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

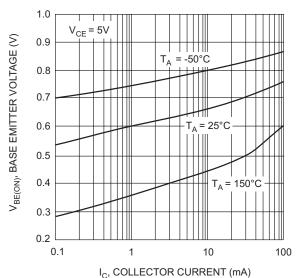


Fig. 4, Base Emitter Voltage
vs. Collector Current



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